



High-Power LED – WICOP Z8 Y50 SZ8-Y50-XX-XX-XX (Cool, Neutral, Warm)





Product Brief

Description

- The WICOP series is designed for high flux output applications with high current operation capability.
- It incorporates state of the art SMD design and low thermal resistant material.
- .
- The WICOP is ideal light sources for directional lighting applications such as Spot Lights, various outdoor applications and high performance torches.

Features and Benefits

Designed for high current operation Low Thermal Resistance A wide CCT range of 2,600~7,000K MacAdam 4 & 5 step ellipse color Binning RoHS compliant Phosphor film directly attached to chip surface

Key Applications

Residential - Replacement lamps Commercial/Industrial – Retail Display Outdoor area - Flood/Street light, High Bay

			Derf New Lee	CRI
Reference Code	Color	ССТ	Part Number	Min
		6500K	S1W0-5050657012-00000000-PS001	
SZ8-Y50-W0-C7-P	Cool White	5700K	S1W0-5050577012-00000000-PS001	
		5000K	S1W0-5050507012-00000000-PS001	_
SZ8-Y50-WN-C7-P	Neutral White	4000K	S1W0-5050407012-00000000-PS001	70
		3500K	S1W0-5050357012-00000000-PS001	_
SZ8-Y50-WW-C7-P	Warm White	3000K	S1W0-5050307012-00000000-PS001	
		2700K	S1W0-5050277012-00000000-PS001	
SZ8-Y50-WN-C8-P	Neutral White	4000K	S1W0-5050408012-00000000-PS001	
		3500K	S1W0-5050358012-00000000-PS001	80
SZ8-Y50-WW-C8-P	Warm White	3000K	S1W0-5050308012-00000000-PS001	_
		2700K	S1W0-5050278012-00000000-PS001	_

Table 1. Product Selection Table



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SZ8-Y50-XX-XX-XX - High-power LED

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Performance Characteristics

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Min.	Nominal	Min.		p. Luminou ux Φ _v ^[3] [Im		Typ. Luminous	
CRI, R _a ^[4]	ССТ [К] ^[1]	Flux [lm]	700mA	1000mA	1500mA	Efficacy [Im/W] @700mA	Part Number
	6500	1120	1180	1534	2006	151	S1W0-5050657012-00000000-PS001
	5700	1120	1220	1586	2074	156	S1W0-5050577012-00000000-PS001
	5000	1120	1260	1638	2142	161	S1W0-5050507012-00000000-PS001
70	4000	1040	1240	1612	2108	158	S1W0-5050407012-00000000-PS001
	3500	1040	1150	1495	2542	147	S1W0-5050357012-00000000-PS001
	3000	1040	1120	1456	1904	143	S1W0-5050307012-00000000-PS001
	2700	1040	1090	1417	1853	139	S1W0-5050277012-00000000-PS001
	4000	970	1060	1378	1802	135	S1W0-5050408012-00000000-PS001
80	3500	970	1020	1326	1734	130	S1W0-5050358012-00000000-PS001
00	3000	900	990	1287	1683	126	S1W0-5050308012-00000000-PS001
	2700	900	950	1235	1615	121	S1W0-5050278012-00000000-PS001

Table 2. Electro Optical Characteristics, I_F = 700mA, T_j=85°C

Note :

(1) Correlated Color Temperature is derived from the CIE 1931 Chromaticity diagram. Color coordinate : ± 0.005 , CCT $\pm 5\%$ tolerance.

- (2) Seoul Semiconductor maintains a tolerance of $\pm 7\%$ on flux and power measurements.
- (3) Φ_V is the total luminous flux output as measured with an integrating sphere.
- (4) Tolerance is ± 2.0 on CRI measurements.

Performance Characteristics

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Table 3. Absolute Maximum Ratings

Parameter	Symbol		Value		Unit
Farameter	Symbol	Min.	Тур.	Max. ^[4]	Unit
Forward Current [1]	I _F	-	0.7	1.5	А
Power Dissipation	P _D	-	-	18	W
Junction Temperature	T_{j}	-	-	145	°C
Storage Temperature	T_{stg}	- 40	-	125	°C
Viewing angle	θ		125		degree
Forward voltage (700mA, 85°C)	V _F		11.0	11.5	V
Thermal resistance (J to S) [2]	$R\theta_{J-S}$	-	0.8 ^[3]	-	K/W
ESD Sensitivity(HBM)		Class 2	JEDEC JS-0	01-2017	

Note :

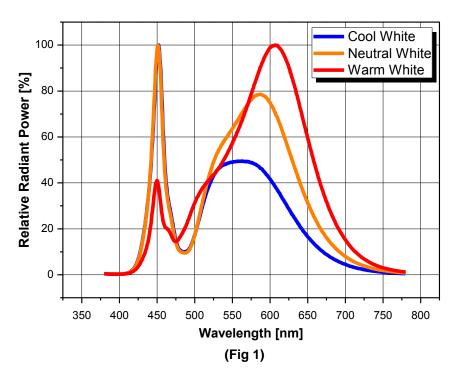
(1) At Junction Temperature 85°C condition.

- (2) $R\theta_{J-S}$ is tested at 700mA.
- (3) Using Metal PCB (Normal type).
- (4) It is recommended to use it in the condition that the reliability is secured within the Max value.
- Thermal resistance can be increased substantially depending on the heat sink design/operating condition, and the maximum possible driving current will decrease accordingly.

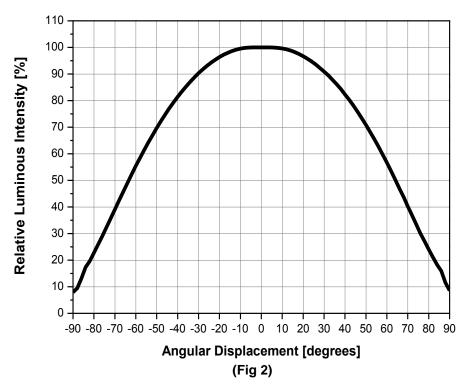
Characteristics Graph

Color Spectrum

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Typical Spatial Distribution

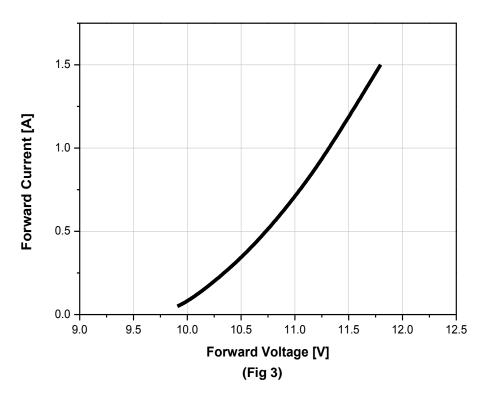




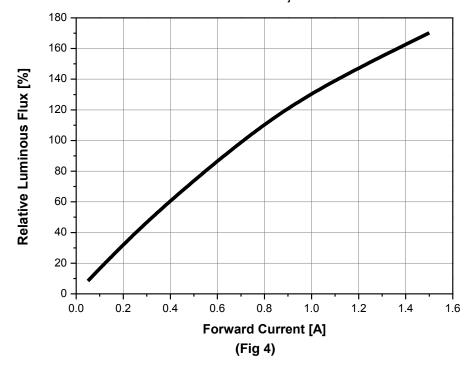
Characteristics Graph

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Forward Voltage vs. Forward Current, T_j=85°C



Forward Current vs. Relative Luminous Flux, T_i=85°C



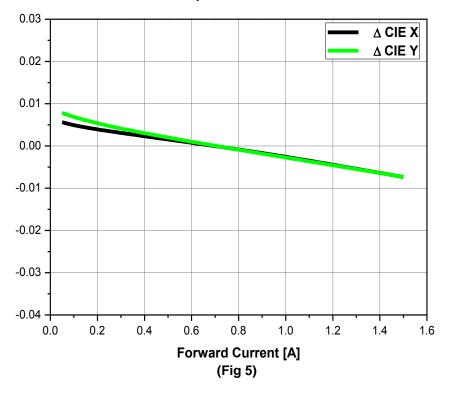
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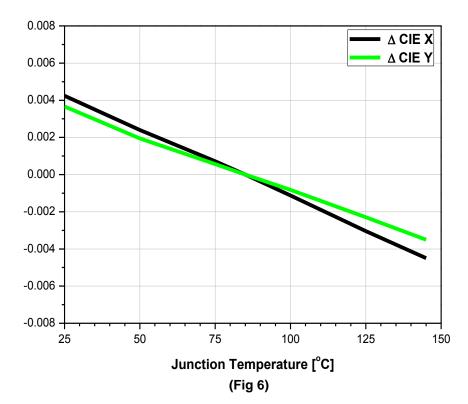
Characteristics Graph

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Forward Current vs. CIE X, Y Shift, T_i=85°C



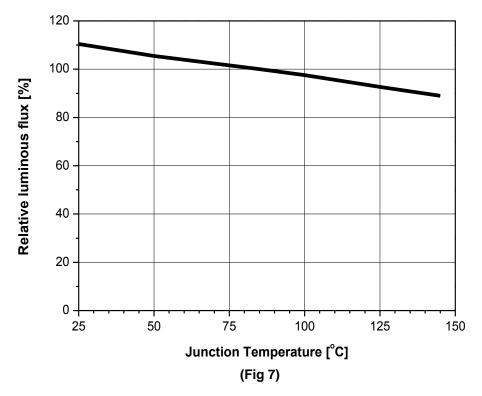
Junction Temp. vs. CIE X, Y Shift, I_F=700mA





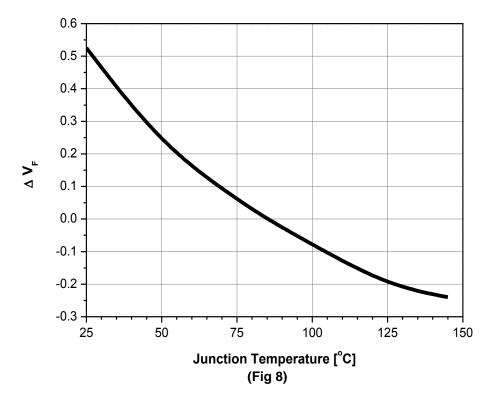
Characteristics Graph

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Junction Temp. vs. Relative Luminous Flux, I_F =700mA

Junction Temp. vs. Relative Forward Voltage, I_F=700mA

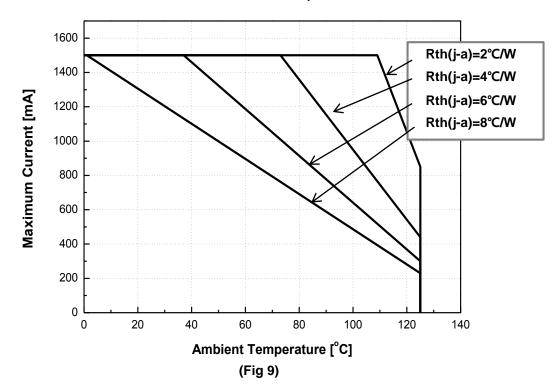


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Characteristics Graph

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Ambient Temp. vs. Maximum Forward Current, Tj(max.)=145°C, IF=1.5A

Color Bin Structure

Table 4. Bin Code description, I_F=700mA, T_i=85°C

<CRI 70>

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Part Number	Lum	inous Flux	[lm]	Color Chromaticity	Typical For	ward Volta	ard Voltage [V _F] ^{[1]*}	
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.	
	Н	1290	1380		F	10.5	10.9	
	G	1200	1290	-	Г		10.8	
S1W0-	F	1120	1200	Refer to page.		40.0	11.0	
5050xx7012- 00000000-PS001	E	1040	1120	12~14	G	10.8	11.2	
					н	11.2	11.5	

Table 5. Luminous Flux rank distribution(CRI70)

Available Rank

ССТ	CIE			Luminous	Flux Rank		
6,000 ~ 7,000K	А	С	D	Е	F	G	н
5,300 – 6,000K	В	С	D	Е	F	G	Н
4,700 ~ 5,300K	С	С	D	E	F	G	Н
3,700 ~ 4,200K	Е	С	D	E	F	G	Н
3,200 ~ 3,700K	F	С	D	E	F	G	Н
2,900 ~ 3,200K	G	С	D	Е	F	G	Н
2,600 ~ 2,900K	Н	С	D	E	F	G	Н

Notes :

(1) Tolerance is $\pm 0.06V$ on forward voltage measurements.

Color Bin Structure

Table 4. Bin Code description, I_F=700mA, T_i=85°C

<CRI 80>

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Part Number	Lum	inous Flux	[lm]	Color Chromaticity	Typical For	ward Volta	ge [V _F] ^{[1]*}
	Bin Code	Min.	Max.	Coordinate	Bin Code	Min.	Max.
	E	1040	1120		F	10.5	10.8
S1W0-	D	970	1040	Refer to page.	G	10.8	11.2
5050xx8012- 00000000-PS001	С	900	970	12~14	Н	11.2	11.5

Table 5. Luminous Flux rank distribution(CRI80)

Available Rank

сст	CIE			Luminous	Flux Rank		
3,700 ~ 4,200K	E	В	С	D	E	F	G
3,200 ~ 3,700K	F	В	С	D	E	F	G
2,900 ~ 3,200K	G	В	С	D	E	F	G
2,600 ~ 2,900K	Н	В	С	D	E	F	G

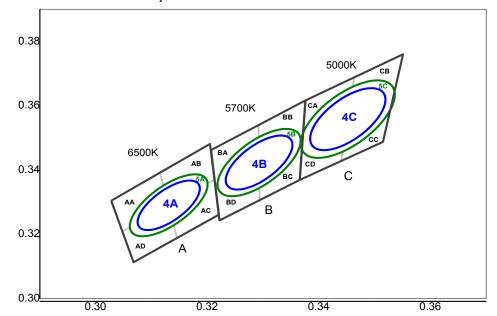
Notes :

(1) Tolerance is $\pm 0.06V$ on forward voltage measurements.

Color Bin Structure

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CIE Chromaticity Diagram, T_j=85°C, I_F=700mA



6500	K 4Step	5700	K 4Step	5000K 4Step		
	4A]	4B	4C		
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0088	Major Axis a	0.0095	Major Axis a	0.0108	
Minor Axis b	0.0036	Minor Axis b	0.0040	Minor Axis b	0.0047	
Ellipse Rotation Angle	58	Ellipse 59 Rotation Angle		Ellipse Rotation Angle	60	

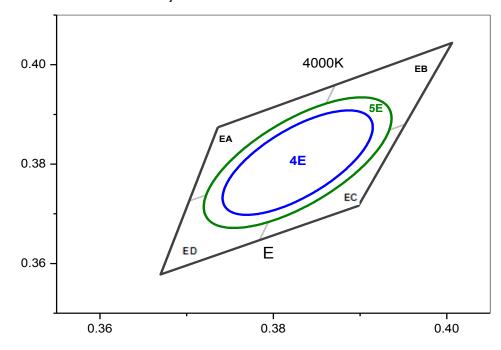
6500	K 5Step	5700	K 5Step	5000K 5Step		
_	5A		5B	5C		
Center point	0.3123 : 0.3282	Center point	0.3287 : 0.3417	Center point	0.3447 : 0.3553	
Major Axis a	0.0110	Major Axis a	0.0118	Major Axis a	0.0135	
Minor Axis b	0.0045	Minor Axis b	0.0050	Minor Axis b	0.0058	
Ellipse Rotation Angle	58	Ellipse 59 Rotation Angle		Ellipse Rotation Angle	60	

A	A	A	В	A	С	A	D
CIE X	CIE Y						
0.3028	0.3304	0.3115	0.3393	0.3131	0.329	0.3048	0.3209
0.3048	0.3209	0.3131	0.329	0.3146	0.3187	0.3068	0.3113
0.3131	0.329	0.3213	0.3371	0.3221	0.3261	0.3146	0.3187
0.3115	0.3393	0.3205	0.3481	0.3213	0.3371	0.3131	0.329
В	A	В	В	В	C	В	D
CIE X	CIE Y						
0.3207	0.3462	0.3292	0.3539	0.3293	0.3423	0.3215	0.3353
0.3215	0.3353	0.3293	0.3423	0.3294	0.3306	0.3222	0.3243
0.3293	0.3423	0.3371	0.3493	0.3366	0.3369	0.3294	0.3306
0.3292	0.3539	0.3376	0.3616	0.3371	0.3493	0.3293	0.3423
C	A	C	В	C	C	C	D
CIE X	CIE Y						
0.3376	0.3616	0.3463	0.3687	0.3452	0.3558	0.3371	0.3493
0.3371	0.3493	0.3452	0.3558	0.344	0.3428	0.3366	0.3369
0.3452	0.3558	0.3533	0.3624	0.3514	0.3487	0.344	0.3428
0.3463	0.3687	0.3551	0.376	0.3533	0.3624	0.3452	0.3558

Color Bin Structure

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CIE Chromaticity Diagram, T_j=85°C, I_F=700mA



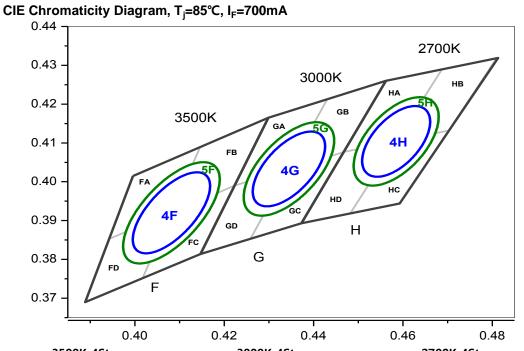
4000K 4Step					
4E					
Center point	0.3818 : 0.3797				
Major Axis a	0.0125				
Minor Axis b	0.0053				
Ellipse	53				
Rotation Angle	53				

4000K 5Step					
5E					
Center point 0.3818 : 0.3797					
Major Axis a	0.0157				
Minor Axis b	0.0067				
Ellipse	50				
Rotation Angle 53					

E	A	E	В	E	c	E	D
CIE X	CIE Y						
0.3736	0.3874	0.3871	0.3959	0.3828	0.3803	0.3703	0.3726
0.3703	0.3726	0.3828	0.3803	0.3784	0.3647	0.367	0.3578
0.3828	0.3803	0.3952	0.388	0.3898	0.3716	0.3784	0.3647
0.3871	0.3959	0.4006	0.4044	0.3952	0.388	0.3828	0.3803

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3500K 4Step		3000K 4Step		2700K 4Step	
	4F		4G		4H
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101
Major Axis a	0.0124	Major Axis a	0.0113	Major Axis a	0.0105
Minor Axis b	0.0055	Minor Axis b	0.0055	Minor Axis b	0.0055
Ellipse	53	Ellipse	53	Ellipse	54
Rotation Angle		Rotation Angle		Rotation Angle	

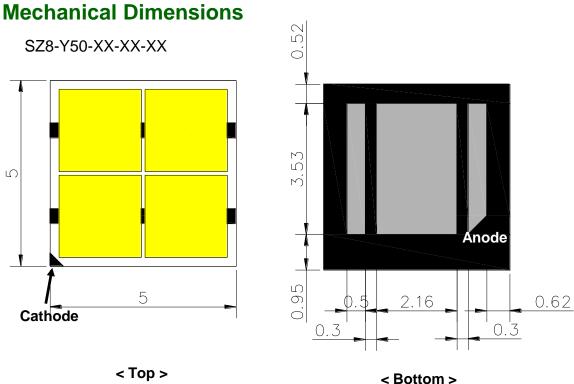
3500	3500K 5Step		3000K 5Step		2700K 5Step	
	5F		5G		5H	
Center point	0.4073 : 0.3917	Center point	0.4338 : 0.4030	Center point	0.4578 : 0.4101	
Major Axis a	0.0155	Major Axis a	0.0142	Major Axis a	0.0132	
Minor Axis b	0.0068	Minor Axis b	0.0068	Minor Axis b	0.0068	
Ellipse	53	Ellipse	53	Ellipse	54	
Rotation Angle	00	Rotation Angle	00	Rotation Angle	04	

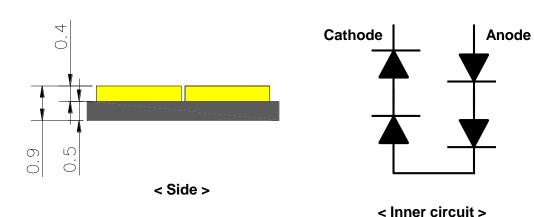
F	Ā	F	В	F	C	F	D
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.3996	0.4015	0.4146	0.4089	0.4082	0.392	0.3943	0.3853
0.3943	0.3853	0.4082	0.392	0.4017	0.3751	0.3889	0.369
0.4082	0.392	0.4223	0.399	0.4147	0.3814	0.4017	0.3751
0.4146	0.4089	0.4299	0.4165	0.4223	0.399	0.4082	0.392
C	G A	G	В	G	c	G	D
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4299	0.4165	0.443	0.4212	0.4345	0.4033	0.4223	0.399
0.4223	0.399	0.4345	0.4033	0.4259	0.3853	0.4147	0.3814
0.4345	0.4033	0.4468	0.4077	0.4373	0.3893	0.4259	0.3853
0.443	0.4212	0.4562	0.426	0.4468	0.4077	0.4345	0.4033
H	IA	н	В	н	C	н	D
CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y	CIE X	CIE Y
0.4562	0.426	0.4687	0.4289	0.4585	0.4104	0.4468	0.4077
0.4468	0.4077	0.4585	0.4104	0.4483	0.3919	0.4373	0.3893
0.4585	0.4104	0.4703	0.4132	0.4593	0.3944	0.4483	0.3919
0.4687	0.4289	0.481	0.4319	0.4703	0.4132	0.4585	0.4104

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(1) All dimensions are in millimeters.

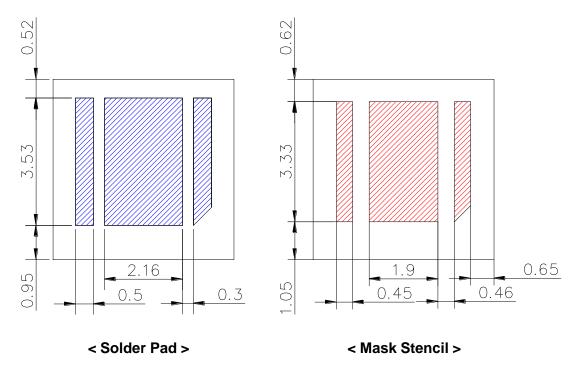
- (2) Scale : none
- (3) Undefined tolerance is ± 0.2 mm



Recommended Solder Pad

SZ8-Y50-XX-XX-XX

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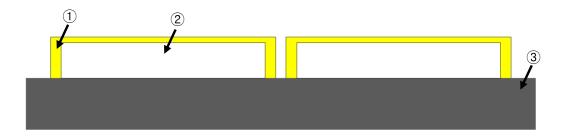
(1) All dimensions are in millimeters.

- (2) Scale : none
- (3) This drawing without tolerances are for reference only.
- (4) Undefined tolerance is ± 0.1 mm.



Material Structure

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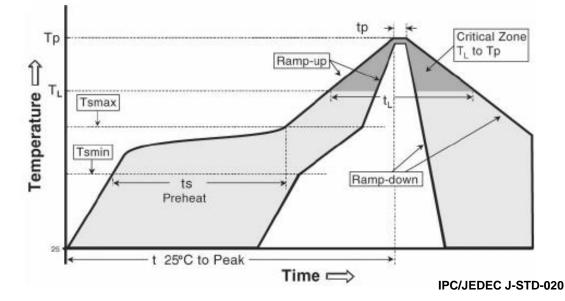
No.	List	Material
1	Encapsulation	Silicone, Phosphor
2	Chip Source	GaN ON SAPPHIRE
3	Substrate	Ceramic (AIN)

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Reflow Soldering Characteristics

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Profile Feature	Pb-Free Assembly
Average ramp-up rate (Tsmax to Tp)	3° C/second max.
Preheat - Temperature Min (Tsmin) - Temperature Max (Tsmax) - Time (Tsmin to Tsmax) (ts)	150 °C 180 °C 80-120 seconds
Time maintained above: - Temperature (TL) - Time (tL)	217~220°C 80-100 seconds
Peak Temperature (Tp)	250~255℃
Time within 5°C of actual Peak Temperature (tp)2	20-40 seconds
Ramp-down Rate	6 °C/second max.
Time 25°C to Peak Temperature	8 minutes max.
Atmosphere	Nitrogen (O2<1000ppm)

Caution

- (1) Reflow soldering is recommended not to be done more than two times. In the case of more than 24 hours passed soldering after first, LED will be damaged.
- (2) Re-soldering should not be done after the LED has been soldered. If re-soldering is
- unavoidable, LED's characteristics should be carefully checked before and after such repair.
- (3) Do not put stress on the LED during heating.
- (4) After reflow, do not clean PCB by water or solvent.

SMT recommendation

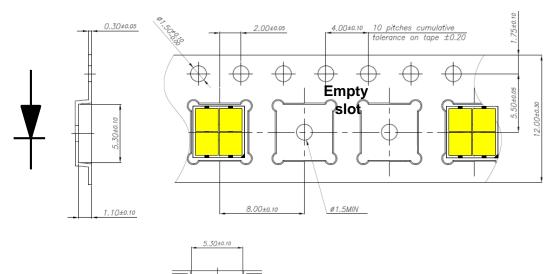
- (1) After reflow, Over 80% reflectance of PSR is recommended. → Tamura RPW-8000-xx
- (2) Solder paste materials (SAC 305, No Cleaning Paste) → Senju M705-GRN360-K2-V
- (3) We recommend TOV Test 7.2v~10.8v at 1uA (per LED)
- (4) We recommend IR Test 0~1uA at -5V (per LED)

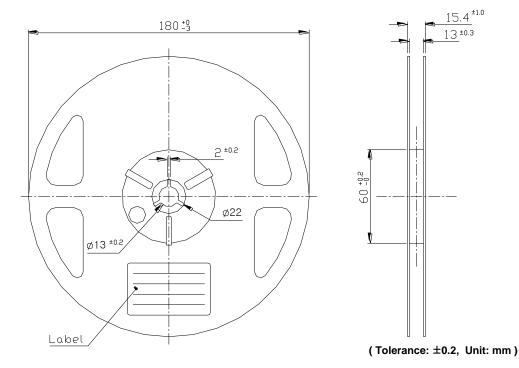


Emitter Tape & Reel Packaging

SZ8-Y50-XX-XX-XX

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Notes :

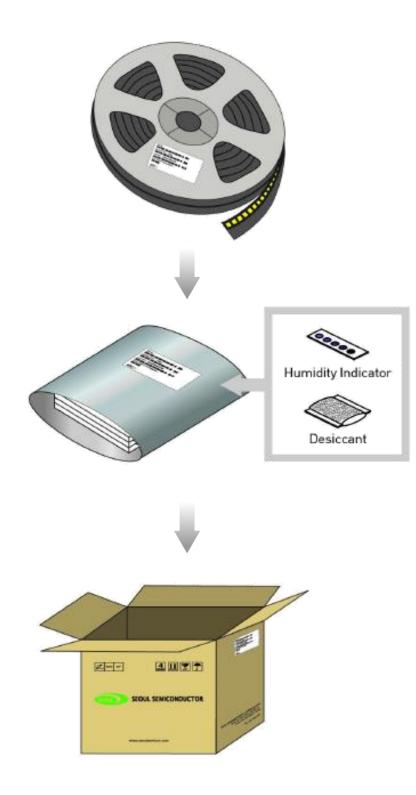
- (1) Quantity : 500pcs/Reel
 - (empty slot is possible in taping reel
 - Continuous empty slot can be max. 3ea and total empty slot is possible max. 10ea.)
- (2) Cumulative Tolerance : Cumulative Tolerance/10 pitches to be $\pm 0.2 \text{mm}$
- (3) Adhesion Strength of Cover Tape : Adhesion strength to be 0.1-0.7N when the cover tape is turned off from the carrier tape at the angle of 10° to the carrier tape
- (4) Package : P/N, Manufacturing data Code No. and quantity to be indicated on a damp proof Package



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Packaging Information



Product Nomenclature

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Table 6. Part Numbering System : $X_1X_2X_3X_4X_5X_6X_7X_8$ - X_9

Part Number Code	Description	Part Number	Value
X ₁	Company	S	Seoul Semiconductor
X ₂	Level of Integration	1	Discrete LED
X ₃ X ₄	Technology	WO	General White
X ₅ X ₆ X ₇ X ₈	Dimension	5050	
X ₉ X ₁₀	ССТ	40	
X ₁₁ X ₁₂	CRI	70	
X ₁₃ X ₁₄	Vf	12	
X ₁₅ X ₁₆ X ₁₇	Characteristic code Flux Rank	000	
X ₁₈ X ₁₉ X ₂₀	Characteristic code Vf Rank	000	
X ₂₁ X ₂₂	Characteristic code Color Step	00	
X ₂₃ X ₂₄	Туре	PS	
X ₂₅ X ₂₆ X ₂₇	Internal code	001	

Notes :

(1) Tolerance is $\pm 0.06V$ on forward voltage measurements.



Handling of Silicone Resin for LED

(1) During processing, mechanical stress on the surface should be minimized as much as possible. Sharp objects of all types should not be used to pierce the sealing compound.



- (2) Do not use tweezers to pick up or handle WICOP LED. A vacuum pick up should only be used.
- (3) When populating boards in SMT production, there are basically no restrictions regarding the form of the pick and place nozzle, except that mechanical pressure on the surface of the resin must be prevented. This is assured by choosing a pick and place nozzle which is smaller than the LED's area.
- (4) Silicone differs from materials conventionally used for the manufacturing of LED. These conditions must be considered during the handling of such devices. Compared to standard encapsulants, silicone is generally softer, and the surface is more likely to attract dust. As mentioned previously, the increased sensitivity to dust requires special care during processing.
- (5) Please do not mold this product into another resin (epoxy, urethane, etc) and do not handle this product with acid or sulfur material in sealed space.
- (6) Avoid leaving fingerprints on silicone resin parts.

Precaution for Use

(1) Storage

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To avoid the moisture penetration, we recommend storing LED in a dry box with a desiccant . The recommended storage temperature range is 5°C to 30°C and a maximum humidity of RH50%.

(2) Use Precaution after Opening the Packaging

Use proper SMD techniques when the LED is to be soldered dipped as separation of the lens may affect the light output efficiency.

Pay attention to the following:

- a. Recommend conditions after opening the package
 - Sealing / Temperature : 5 ~ 30°C Humidity : less than RH60%
- b. If the package has been opened more than 1 year (MSL 2) or the color of

the desiccant changes, components should be dried for 10-24hr at $65\pm5^\circ$ C

(3) Do not apply mechanical force or excess vibration during the cooling process to normal temperature after soldering.

(4) Do not rapidly cool device after soldering.

(5) Components should not be mounted on warped (non coplanar) portion of PCB.

(6) Radioactive exposure is not considered for the products listed here in.

(7) Gallium arsenide is used in some of the products listed in this publication. These products are dangerous if they are burned or shredded in the process of disposal. It is also dangerous to drink the liquid or inhale the gas generated by such products when chemically disposed of.

(8) This device should not be used in any type of fluid such as water, oil, organic solvent and etc.

(9) When the LED is in operation the maximum current should be decided after measuring the package temperature.

(10) The appearance and specifications of the product may be modified for improvement without notice.

(11) Long time exposure of sunlight or occasional UV exposure will cause lens discoloration.

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SZ8-Y50-XX-XX-XX - High-power LED

Precaution for Use

(12) VOCs (Volatile organic compounds) emitted from materials used in the construction of fixtures ca n penetrate silicone encapsulants of LED and discolor when exposed to heat and photonic energy. Th e result can be a significant loss of light output from the fixture. Knowledge of the properties of the mat erials selected to be used in the construction of fixtures can help prevent these issues.

(13) The slug is electrically isolated.

(14) Attaching LED, do not use adhesives that outgas organic vapor.

(15) The driving circuit must be designed to allow forward voltage only when it is ON or OFF. If the rev erse voltage is applied to LED, migration can be generated resulting in LED damage.

(16) LED is sensitive to Electro-Static Discharge (ESD) and Electrical Over Stress (EOS). Below is a li st of suggestions that Seoul Semiconductor purposes to minimize these effects.

a. ESD (Electro Static Discharge)

Electrostatic discharge (ESD) is the defined as the release of static electricity when two objects come into contact. While most ESD events are considered harmless, it can be an expensive problem in many industrial environments during production and storage. The damage from ESD to an LED may c ause the product to demonstrate unusual characteristics such as:

- Increase in reverse leakage current lowered turn-on voltage
- Abnormal emissions from the LED at low current

The following recommendations are suggested to help minimize the potential for an ESD event. One or more recommended work area suggestions:

- Ionizing fan setup
- ESD table/shelf mat made of conductive materials
- ESD safe storage containers

One or more personnel suggestion options:

- Antistatic wrist-strap
- Antistatic material shoes
- Antistatic clothes

Environmental controls:

- Humidity control (ESD gets worse in a dry environment)



Company Information

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Company Information

Seoul Semiconductor (www.SeoulSemicon.com) manufacturers and packages a wide selection of light emitting diodes (LEDs) for the automotive, general illumination/lighting, Home appliance, signage and back lighting markets. The company is the world's fifth largest LED supplier, holding more than 10,000 patents globally, while offering a wide range of LED technology and production capacity in areas such as "nPola", "Acrich", the world's first commercially produced AC LED, and "Acrich MJT - Multi-Junction Technology" a proprietary family of high-voltage LEDs.

The company's broad product portfolio includes a wide array of package and device choices such as Acrich and Acirch2, high-brightness LEDs, mid-power LEDs, side-view LEDs, and through-hole type LEDs as well as custom modules, displays, and sensors.

Legal Disclaimer

Information in this document is provided in connection with Seoul Semiconductor products. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Seoul Semiconductor hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party. The appearance and specifications of the product can be changed to improve the quality and/or performance without notice.



Precaution for Use

b. EOS (Electrical Over Stress)

Electrical Over-Stress (EOS) is defined as damage that may occur when an electronic device is subjected to a current or voltage that is beyond the maximum specification limits of the device. The effects from an EOS event can be noticed through product performance like:

- Changes to the performance of the LED package

(If the damage is around the bond pad area and since the package is completely encapsulated the package may turn on but flicker show severe performance degradation.)

- Changes to the light output of the luminaire from component failure
- Components on the board not operating at determined drive power

Failure of performance from entire fixture due to changes in circuit voltage and current across total circuit causing trickle down failures. It is impossible to predict the failure mode of every LED exposed to electrical overstress as the failure modes have been investigated to vary, but there are some common signs that will indicate an EOS event has occurred:

- This damage usually appears due to the thermal stress produced during the EOS event.

c. To help minimize the damage from an EOS event Seoul Semiconductor recommends utilizing:

- A surge protection circuit
- An appropriately rated over voltage protection device
- A current limiting device